

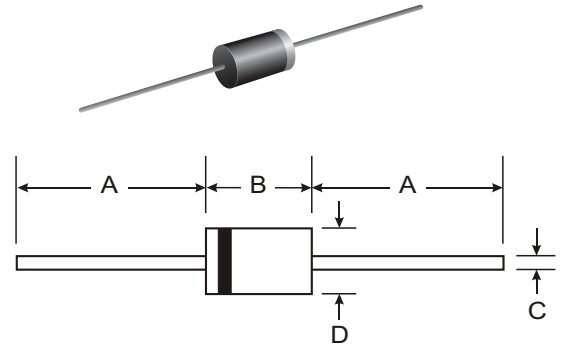
**VOLTAGE RANGE: 100V**  
**CURRENT: 1.0 A**

### Features

- Miniature Size
- Low Forward Voltage drop
- Low Reverse Leakage Current
- High Surge Capability

### Mechanical Data

- Case: D O - 4 1 Molded Plastic
- Terminals: Plated Leads Solderable per MIL-STD-202, Method 208
- Polarity: Cathode Band
- Weight: 0.34 grams (approx.)
- Mounting Position: Any
- Marking: Type Number



DO-41		
Dim	Min	Max
A	25.40	—
B	4.06	5.21
C	0.71	0.864
D	2.00	2.72
All Dimensions in mm		

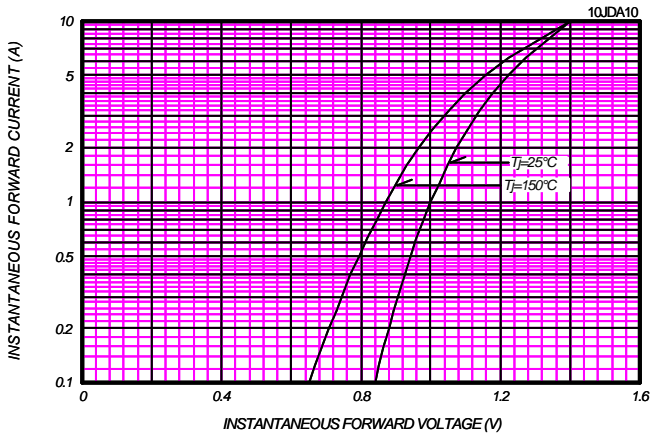
### Maximum Ratings @ T<sub>A</sub> = 25°C unless otherwise specified

Characteristic	Symbol	10JDA10		Unit	
Repetitive Peak Reverse Voltage	V <sub>RRM</sub>	100		V	
Average Rectified Output Current	I <sub>O</sub>	50Hz Half Sine Wave Resistive Load	T <sub>a</sub> =29°C *1	1.0	A
			T <sub>l</sub> =126°C (T <sub>l</sub> : Lead Temperature)	1.0	
RMS Forward Current	I <sub>F(RMS)</sub>			1.57	A
Surge Forward Current	I <sub>FSM</sub>	50Hz Half Sine Wave, 1cycle, Non-repetitive		45	A
Operating Junction Temperature Range	T <sub>jw</sub>	- 40 to + 150		°C	
Storage Temperature Range	T <sub>stg</sub>	- 40 to + 150		°C	

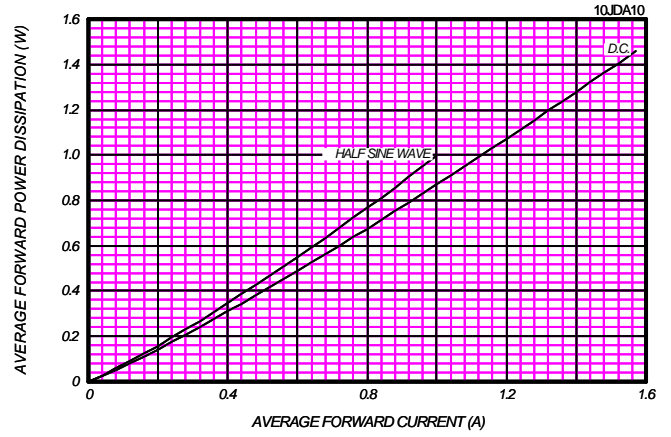
### Electrical Characteristics

Characteristics	Symbol	Conditions	Min.	Typ.	Max.	Unit
Peak Reverse Current	I <sub>RM</sub>	T <sub>j</sub> = 25 °C, V <sub>RM</sub> = V <sub>RRM</sub>	-	-	10	μA
Peak Forward Voltage	V <sub>FM</sub>	T <sub>j</sub> = 25 °C, I <sub>FM</sub> = 1.0A	-	-	1.0	V
Thermal Resistance	R <sub>th(j-a)</sub>	Junction to Ambient *1	-	-	120	°C/W
	R <sub>th(j-l)</sub>	Junction to Lead	-	-	23	

FORWARD CURRENT VS. VOLTAGE

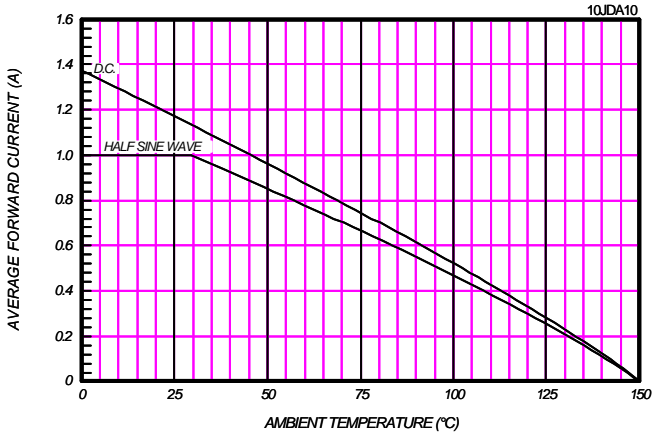


AVERAGE FORWARD POWER DISSIPATION

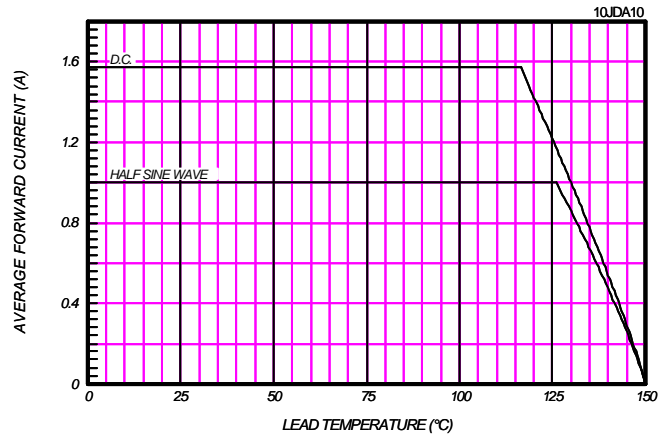


AVERAGE FORWARD CURRENT VS. AMBIENT TEMPERATURE

AMBIENT/Without Fin or P.C. Board



AVERAGE FORWARD CURRENT VS. LEAD TEMPERATURE



SURGE CURRENT RATINGS

f=50Hz, Half Sine Wave, Non-Repulsive, No Load

